

Ion-Gel-Gated Graphene Optical Switch

Jin Tae Kim

Hongkyw Choi

Creative Future Research Laboratory,
Electronics and Telecommunications Research
Institute (ETRI), Daejeon 34129, South
Korea

jjintae@etri.re.kr

In this work, we designed and fabricated a graphene-integrated polymer waveguide switch whose optical modulation was controlled by an ion-gel top-gate dielectric. Simple spin coating of a polymer resin and a dry-etching process allowed the fabrication of the photonic integrated circuit platform. Comparatively accurate positioning of the transferred graphene and ion gel on the photonic platform allowed us to develop the all-dielectric in-line graphene photonic integrated circuits.

The electro-absorption characteristics of the fabricated photonic device were investigated by numerical simulations and experimental measurements. The ion-gel dielectric played a key role in modulating the power of the light wave as a transparent upper-cladding medium, increasing the light-graphene interaction ratio. By applying the gate voltage, the optical output power of the switch was tunable. Uniquely, the gate voltage-dependent optical properties of the device exhibit a large hysteresis, which originates from the slow polarization response time of ions.

The photonic device is applicable to both TE- and TM-polarized light waves, covering two entire optical communication bands, the O-band (1.26–1.36 μm) and the C-band (1.52–1.565 μm). The experimental results are in good agreement with theoretically simulated predictions. The temporal behavior of the ion-gel-graphene-integrated optical switch reveals a long-term modulation state because of the relatively low mobility of the ions in the ion-gel solution and formation of the electric

double layer in the graphene-ion-gel interface. Fast dynamic recovery is observed by applying an opposite voltage gate pulse.

References

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Figures

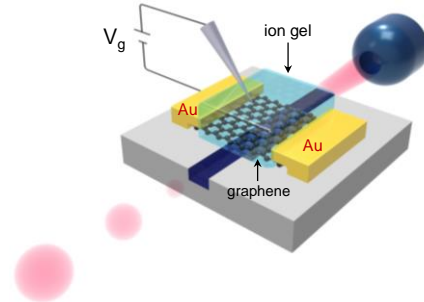


Figure 1: Bird's-eye view of the designed graphene-ion-gel-integrated optical switch

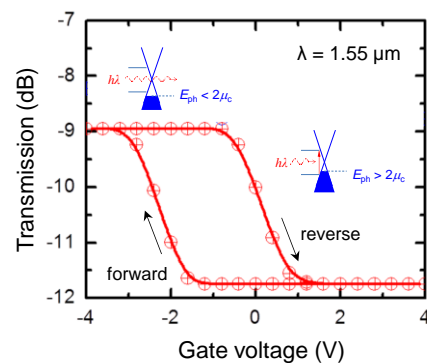


Figure 2: Optical transmission of the graphene-ion-gel-integrated optical waveguide switch according to the top-gate electric voltage, V_g .